MICROCHIP TC4426A/TC4427A/TC4428A

1.5A Dual High-Speed Power MOSFET Drivers

Features:

- High Peak Output Current 1.5A
- Wide Input Supply Voltage Operating Range:
 4.5V to 18V
- High Capacitive Load Drive Capability 1000 pF in 25 ns (typ.)
- Short Delay Times 30 ns (typ.)
- Matched Rise, Fall and Delay Times
- Low Supply Current:
 - With Logic '1' Input 1 mA (typ.)
- With Logic '0' Input 100 μA (typ.)
- Low Output Impedance 7Ω (typ.)
- Latch-Up Protected: Will Withstand 0.5A Reverse Current
- Input Will Withstand Negative Inputs Up to 5V
- ESD Protected 4 kV
- Pin-compatible with TC426/TC427/TC428 and TC4426/TC4427/TC4428
- Space-saving 8-Pin MSOP and 8-Pin 6x5 DFN Packages

Applications:

- Switch Mode Power Supplies
- Line Drivers
- Pulse Transformer Drive

General Description:

The TC4426A/TC4427A/TC4428A are improved versions of the earlier TC4426/TC4427/TC4428 family of MOSFET drivers. In addition to matched rise and fall times, the TC4426A/TC4427A/TC4428A devices have matched leading and falling edge propagation delay times.

These devices are highly latch-up resistant under any conditions within their power and voltage ratings. They are not subject to damage when up to 5V of noise spiking (of either polarity) occurs on the ground pin. They can accept, without damage or logic upset, up to 500 mA of reverse current (of either polarity) being forced back into their outputs. All terminals are fully protected against Electrostatic Discharge (ESD) up to 4 kV.

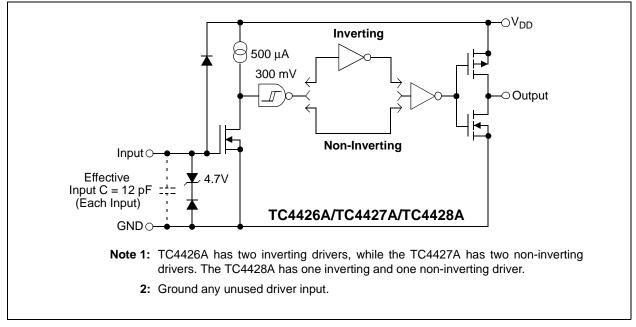
The TC4426A/TC4427A/TC4428A MOSFET drivers can easily charge/discharge 1000 pF gate capacitances in under 30 ns. These devices provide low enough impedances in both the on and off states to ensure the MOSFET's intended state will not be affected, even by large transients.

Package Types

	\ TC4427A	TC4428A	8-	Pin DFN ⁽¹	, TC4426A	TC4427A	TC4428A
NC 1 • 8 NC A 2 TC4426A 7 OUT A	NC ^V OUT A		NC 1		8 NC	NC	NC
ND 3 TC4427A 6 V _{DD}	V _{DD}	V _{DD}	IN A 2	TC4426A TC4427A	7 OUT A	OUT A	OUT A
NB4TC4428A5 OUT B	OUT B	OUT B	GND 3	TC4428A	6 V _{DD}	V _{DD}	V _{DD}
			IN B 4		5 OUT B	OUT B	OUT B

TC4426A/TC4427A/TC4428A

Functional Block Diagram



1.0 ELECTRICAL CHARACTERISTICS

Absolute	Maximum	Ratings†
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+22V
GND – 5V)
Note 2
340 mW
730 mW
470 mW

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operation sections of the specifications is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

DC CHARACTERISTICS

Parameters	Sym	Min	Тур	Мах	Units	Conditions
Input						
Logic '1', High Input Voltage	VIH	2.4	_	_	V	
Logic '0', Low Input Voltage	V _{IL}	_	_	0.8	V	
Input Current	I _{IN}	-1.0 -10		+1.0 +10	μA	$0V \le V_{IN} \le V_{DD}$
Output					1	I
High Output Voltage	V _{OH}	V _{DD} - 0.025	_	_	V	DC Test
Low Output Voltage	V _{OL}	_	_	0.025	V	DC Test
Output Resistance	R _O	 	7 7 8 8	9 10 11 12	Ω	$\begin{split} I_{OUT} &= 10 \text{ mA}, \text{ V}_{DD} = 18 \text{ V}, \text{ T}_{A} = +25^{\circ}\text{C} \\ 0^{\circ}\text{C} &\leq \text{T}_{A} \leq +70^{\circ}\text{C} \\ -40^{\circ}\text{C} &\leq \text{T}_{A} \leq +85^{\circ}\text{C} \\ -40^{\circ}\text{C} &\leq \text{T}_{A} \leq +125^{\circ}\text{C} \end{split}$
Peak Output Current	I _{PK}	_	1.5	_	А	$V_{DD} = 18V$
Latch-Up Protection Withstand Reverse Current	I _{REV}	—	> 0.5		A	Duty cycle ≤ 2%, t ≤ 300 µsec V _{DD} = 18V
Switching Time (Note 1)	1					
Rise Time	t _R	 	25 27 29 30	35 40 40 40	ns	$\begin{array}{l} T_{A} = +25^{\circ}C\\ 0^{\circ}C &\leq T_{A} &\leq +70^{\circ}C\\ -40^{\circ}C &\leq T_{A} &\leq +85^{\circ}C\\ -40^{\circ}C &\leq T_{A} &\leq +125^{\circ}C, \mbox{ Figure 4-1} \end{array}$
Fall Time	t _F	 	25 27 29 30	35 40 40 40	ns	$\begin{array}{l} T_{A} = +25^{\circ}C\\ 0^{\circ}C &\leq T_{A} &\leq +70^{\circ}C\\ -40^{\circ}C &\leq T_{A} &\leq +85^{\circ}C\\ -40^{\circ}C &\leq T_{A} &\leq +125^{\circ}C, \mbox{ Figure 4-1} \end{array}$
Delay Time	t _{D1}	 	30 33 35 38	35 40 45 50	ns	$T_{A} = +25^{\circ}C$ $0^{\circ}C \le T_{A} \le +70^{\circ}C$ $-40^{\circ}C \le T_{A} \le +85^{\circ}C$ $-40^{\circ}C \le T_{A} \le +125^{\circ}C, \text{ Figure 4-1}$
Delay Time	t _{D2}	 	30 33 35 38	35 40 45 50	ns	$T_A = +25^{\circ}C$ $0^{\circ}C \le T_A \le +70^{\circ}C$ $-40^{\circ}C \le T_A \le +85^{\circ}C$ $-40^{\circ}C \le T_A \le +125^{\circ}C, \text{ Figure 4-1}$
Power Supply						· · · · · ·
Power Supply Current	۱ _S		1.0 0.1	2.0 0.2	mA	V _{IN} = 3V (Both inputs) V _{IN} = 0V (Both inputs), V _{DD} = 18V

Note 1: Switching times ensured by design.

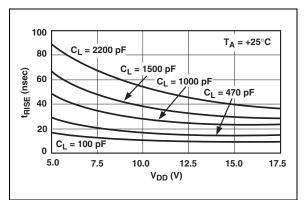
2: Package power dissipation is dependent on the copper pad area on the PCB.

TEMPERATURE CHARACTERISTICS

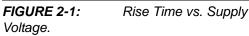
Parameters	Sym	Min	Тур	Max	Units	Conditions
Temperature Ranges		•	•	•		
Specified Temperature Range (C)	T _A	0		+70	°C	
Specified Temperature Range (E)	Τ _Α	-40		+85	°C	
Specified Temperature Range (V)	T _A	-40		+125	°C	
Maximum Junction Temperature	ТJ	_		+150	°C	
Storage Temperature Range	Τ _Α	-65		+150	°C	
Package Thermal Resistances		•				
Thermal Resistance, 8L-6x5 DFN	θ_{JA}	_	33.2	_	°C/W	
Thermal Resistance, 8L-MSOP	θ_{JA}	_	206		°C/W	
Thermal Resistance, 8L-PDIP	θ_{JA}	—	125		°C/W	
Thermal Resistance, 8L-SOIC	θ_{JA}	—	155	_	°C/W	

2.0 **TYPICAL PERFORMANCE CURVES**

The graphs and tables provided following this note are a statistical summary based on a limited number of Note: samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.



Note: Unless otherwise indicated, over operating temperature range with 4.5V \leq V_{DD} \leq 18V.



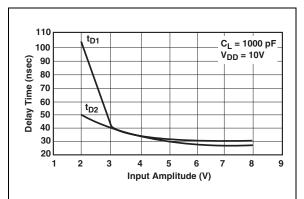


FIGURE 2-2: Delay Time vs. Input Amplitude.

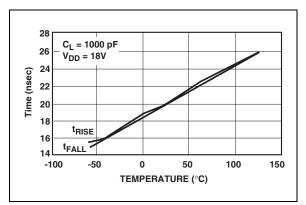


FIGURE 2-3: Rise and Fall Times vs. Temperature.

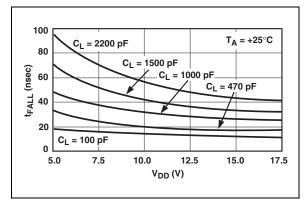


FIGURE 2-4: Fall Time vs. Supply Voltage.

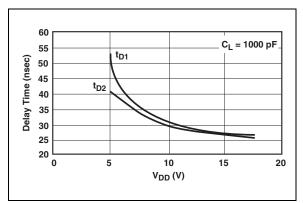
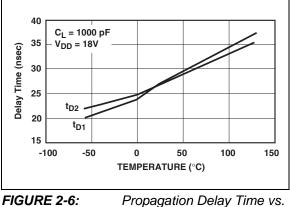


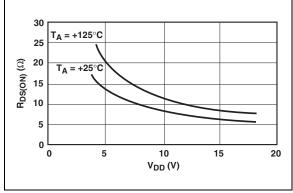
FIGURE 2-5: Propagation Delay Time vs. Supply Voltage.

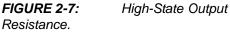


Temperature.

TC4426A/TC4427A/TC4428A

Note: Unless otherwise indicated, over operating temperature range with 4.5V \leq V_{DD} \leq 18V.





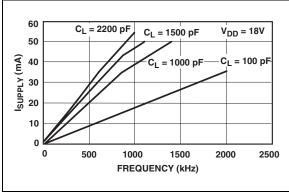


FIGURE 2-8: Supply Current vs. Frequency.

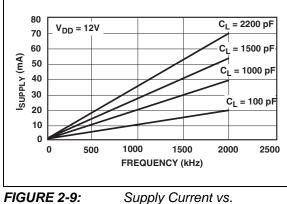


FIGURE 2-9: Frequency.

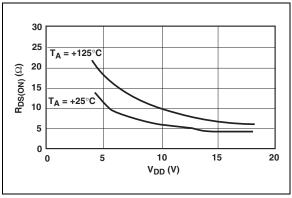


FIGURE 2-10: Low-State Output Resistance.

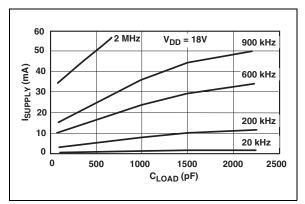


FIGURE 2-11: Supply Current vs. Capacitive Load.

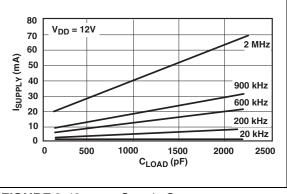
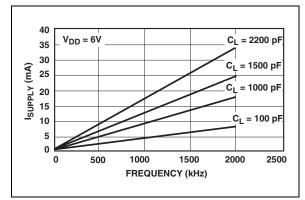


FIGURE 2-12: Supply Current vs. Capacitive Load.

Note: Unless otherwise indicated, over operating temperature range with 4.5V $\,\leq V_{DD} \,{\leq}\, 18V.$





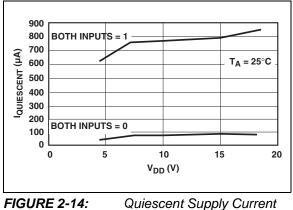


FIGURE 2-14: Qu vs. Voltage.

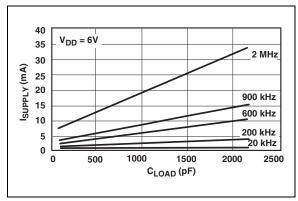


FIGURE 2-15: Supply Current vs. Capacitive Load.

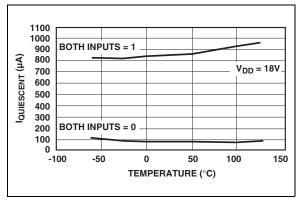


FIGURE 2-16: Quiescent Supply Current vs. Temperature.

3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

IADLE 3-1:	FINTUNC	TION TABLE	
8-Pin PDIP/ MSOP/SOIC	8-Pin DFN	Symbol	Description
1	1	NC	No connection
2	2	IN A	Input A
3	3	GND	Ground
4	4	IN B	Input B
5	5	OUT B	Output B
6	6	V _{DD}	Supply input
7	7	OUT A	Output A
8	8	NC	No connection
	PAD	NC	Exposed Metal Pad

TABLE 3-1: PIN FUNCTION TABLE

Note 1: Duplicate pins must be connected for proper operation.

3.1 Inputs A and B

MOSFET driver inputs A and B are high-impedance, TTL/CMOS compatible inputs. These inputs also have 300 mV of hysteresis between the high and low thresholds that prevents output glitching, even when the rise and fall time of the input signal is very slow.

3.2 Ground (GND)

The ground pin is the return path for both the bias current and the high peak current that discharges the external load capacitance. The ground pin should be tied into a ground plane or have a very short trace to the bias supply source return.

3.3 Output A and B

MOSFET driver outputs A and B are low-impedance, CMOS push-pull style outputs. The pull-down and pullup devices are of equal strength, making the rise and fall times equivalent.

3.4 Supply Input (V_{DD})

The V_{DD} input is the bias supply for the MOSFET driver and is rated for 4.5V to 18V, with respect to the ground pin. The V_{DD} input should be bypassed with local ceramic capacitors. The value of these capacitors should be chosen based on the capacitive load that is being driven.

3.5 Exposed Metal Pad

The exposed metal pad of the 6x5 DFN package is not internally connected to any potential. Therefore, this pad can be connected to a ground plane or other copper plane on a printed circuit board, to aid in heat removal from the package.

4.0 APPLICATIONS INFORMATION

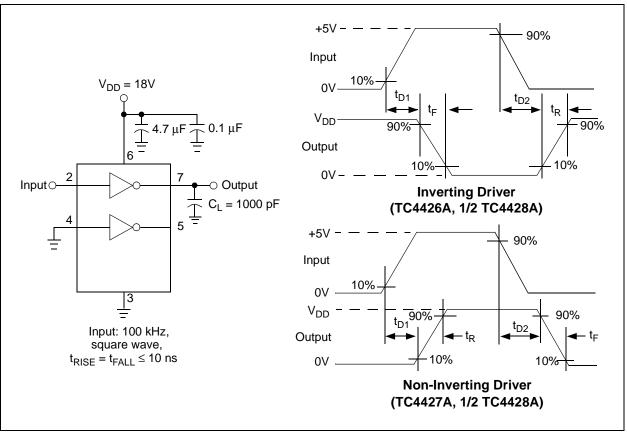
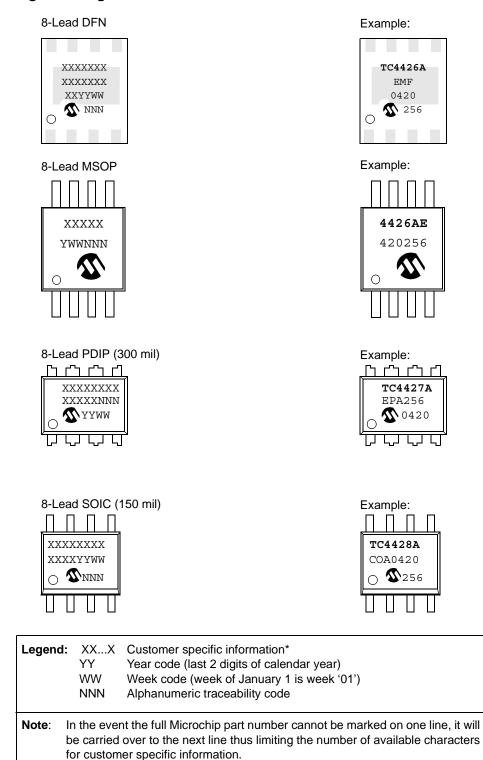


FIGURE 4-1: Switching Time Test Circuit.

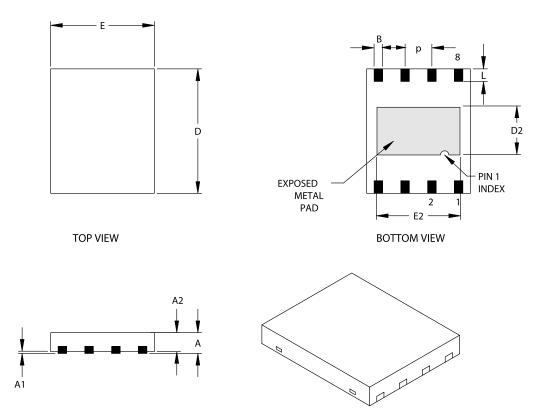
5.0 PACKAGING INFORMATION

5.1 Package Marking Information



* Standard marking consists of Microchip part number, year code, week code, traceability code (facility code, mask rev#, and assembly code).

8-Lead Plastic Dual Flat No Lead Package (MF) 6x5 mm Body (DFN-S) – Saw Singulated



	Units		INCHES		М	ILLIMETERS*	
Dimension Li	mits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.050 BSC		1.27 BSC		
Overall Height	A	.033	.035	.037	0.85	0.90	0.95
Package Thickness	A2	.031	.035	.037	0.80	0.89	0.95
Standoff	A1	.000	.0004	.002	0.00	0.01	0.05
Base Thickness	A3	.007	.008	.009	0.17	0.20	0.23
Overall Length	E	.195	.197	.199	4.95	5.00	5.05
Exposed Pad Length	E2	.152	.157	.163	3.85	4.00	4.15
Overall Width	D	.234	.236	.238	5.95	6.00	6.05
Exposed Pad Width	D2	.089	.091	.093	2.25	2.30	2.35
Lead Width	В	.014	.016	.019	0.35	0.40	0.47
Lead Length	L	.024		.026	0.60		0.65

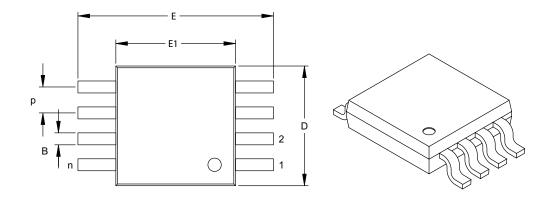
Notes:

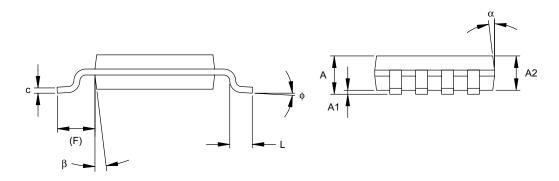
JEDEC equivalent: MO-220

Drawing No. C04-122

Revised 11/3/03

8-Lead Plastic Micro Small Outline Package (UA) (MSOP)





	Units		INCHES		М	ILLIMETERS	*
Dimension Li	mits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.026 BSC			0.65 BSC	
Overall Height	Α	-	-	.043	-	-	1.10
Molded Package Thickness	A2	.030	.033	.037	0.75	0.85	0.95
Standoff	A1	.000	-	.006	0.00	-	0.15
Overall Width	E		.193 TYP.			4.90 BSC	
Molded Package Width	E1		.118 BSC			3.00 BSC	
Overall Length	D		.118 BSC			3.00 BSC	
Foot Length	L	.016	.024	.031	0.40	0.60	0.80
Footprint (Reference)	F		.037 REF			0.95 REF	
Foot Angle	φ	0°	-	8°	0°	-	8°
Lead Thickness	С	.003	.006	.009	0.08	-	0.23
Lead Width	В	.009	.012	.016	0.22	-	0.40
Mold Draft Angle Top	α	5°	-	15°	5°	-	15°
Mold Draft Angle Bottom	β	5°	-	15°	5°	-	15°
*Controlling Doromotor	-						

*Controlling Parameter

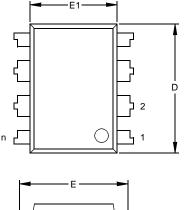
Notes:

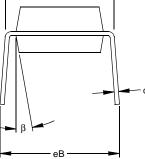
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

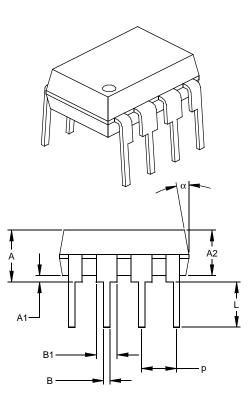
JEDEC Equivalent: MO-187

Drawing No. C04-111

8-Lead Plastic Dual In-line (PA) – 300 mil (PDIP)







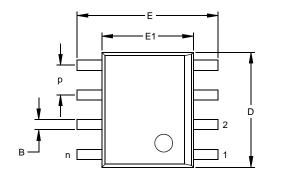
	Units	s INCHES*			MILLIMETERS		
Dimensio	n Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.100			2.54	
Top to Seating Plane	А	.140	.155	.170	3.56	3.94	4.32
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68
Base to Seating Plane	A1	.015			0.38		
Shoulder to Shoulder Width	Е	.300	.313	.325	7.62	7.94	8.26
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60
Overall Length	D	.360	.373	.385	9.14	9.46	9.78
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56
Overall Row Spacing §	eB	.310	.370	.430	7.87	9.40	10.92
Mold Draft Angle Top	α	5	10	15	5	10	15
Mold Draft Angle Bottom	β	5	10	15	5	10	15

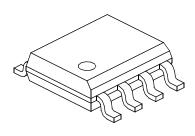
* Controlling Parameter § Significant Characteristic

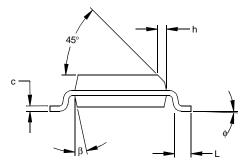
Notes:

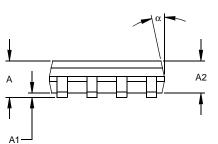
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side. JEDEC Equivalent: MS-001 Drawing No. C04-018

8-Lead Plastic Small Outline (OA) - Narrow, 150 mil (SOIC)









	Units	Units INCHES*			MILLIMETERS		
Dimensio	n Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.050			1.27	
Overall Height	Α	.053	.061	.069	1.35	1.55	1.75
Molded Package Thickness	A2	.052	.056	.061	1.32	1.42	1.55
Standoff §	A1	.004	.007	.010	0.10	0.18	0.25
Overall Width	Е	.228	.237	.244	5.79	6.02	6.20
Molded Package Width	E1	.146	.154	.157	3.71	3.91	3.99
Overall Length	D	.189	.193	.197	4.80	4.90	5.00
Chamfer Distance	h	.010	.015	.020	0.25	0.38	0.51
Foot Length	L	.019	.025	.030	0.48	0.62	0.76
Foot Angle	φ	0	4	8	0	4	8
Lead Thickness	С	.008	.009	.010	0.20	0.23	0.25
Lead Width	В	.013	.017	.020	0.33	0.42	0.51
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15

* Controlling Parameter

§ Significant Characteristic

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side. JEDEC Equivalent: MS-012

Drawing No. C04-057

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO. X	<u>xx</u>	<u>xxx</u>	×	Examples:	
Device Temper Rang	rature Package	 Tape & Reel	PB Free	a) TC4426ACOA:	1.5A Dual Inverting MOSFET driver, 0°C to +70°C, 8LD SOIC package.
Device:	TC4426A: 1.5A Dual TC4427A: 1.5A Dual TC4428A: 1.5A Dual	MOSFET Driver,	Non-Inverting	b) TC4426AEOA:	1.5A Dual Inverting MOSFET driver, -40°C to +85°C, 8LD SOIC package.
Temperature Range:	$\begin{array}{rcl} C & = & 0^{\circ}C \text{ to } +70^{\circ}C \\ E & = & -40^{\circ}C \text{ to } +85^{\circ} \\ V & = & -40^{\circ}C \text{ to } +125 \end{array}$		nly)	c) TC4426AEMF:	1.5A Dual Inverting MOSFET driver, -40°C to +85°C, 8LD DFN package.
Package:	MF713 = Dual, Flat, (Tape and		m Body), 8-lead	a) TC4427ACPA:	1.5A Dual Non-Inverting MOSFET driver, 0°C to +70°C, 8LD PDIP package.
	OA = Plastic SO OA713 = Plastic SO (Tape and UA = Plastic Mic	IC, (150 mil Body IC, (150 mil Body Reel) ro Small Outline (), 8-lead), 8-lead (MSOP), 8-lead	b) TC4427AEPA:	1.5A Dual Non-Inverting MOSFET driver, -40°C to +85°C, 8LD PDIP package.
	UA713 = Plastic Micro Small Outline (MSOP), 8-lead (Tape and Reel)		c) TC4427AVMF713:	1.5A Dual Non-Inverting MOSFET driver, -40°C to +125°C, 8LD DFN package,	
				a) TC4428AEPA:	Tape and Reel. 1.5A Dual Complementary MOSFET driver, -40°C to +85°C, 8LD PDIP package.
				b) TC4428ACOA713:	1.5A Dual Complementary MOSFET driver, 0°C to +70°C 8LD SOIC package, Tape and Reel.
				c) TC4428AVMF:	1.5A Dual Complementary MOSFET driver, -40°C to +125°C, 8LD DFN package.

Sales and Support

Data Sheets

Products supported by a preliminary Data Sheet may have an errata sheet describing minor operational differences and recommended workarounds. To determine if an errata sheet exists for a particular device, please contact one of the following:

- 1. Your local Microchip sales office
- 2. The Microchip Corporate Literature Center U.S. FAX: (480) 792-7277
- 3. The Microchip Worldwide Site (www.microchip.com)

Please specify which device, revision of silicon and Data Sheet (include Literature #) you are using.

Customer Notification System

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NOTES:

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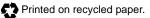
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